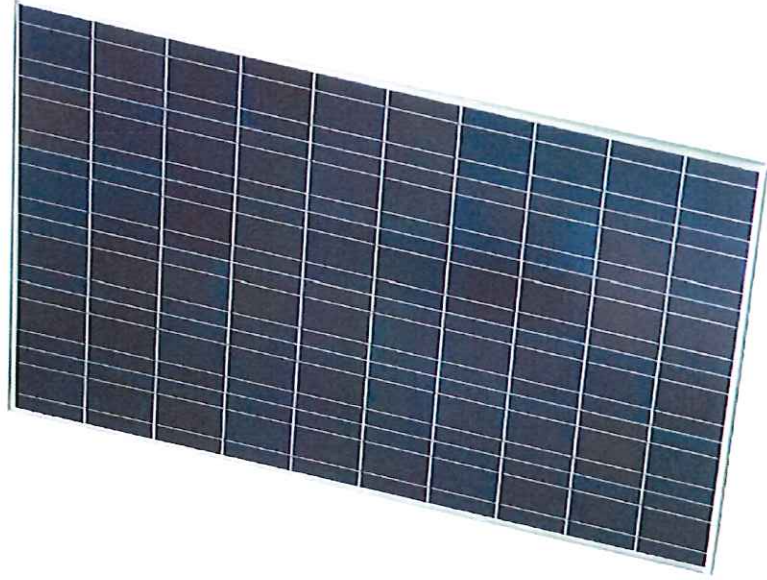


# ローコスト・ハイパフォーマンスな直輸入モデル:EGINGデビュー!

優れたコストパフォーマンス!

**EG-240P60-C**



**最大出力:250W**  
**モジュール変換効率:15.3%**

信頼と安心の認証

耐PID試験に合格



Technical Report No. 70.495.12.1308.01  
Rev. 00  
Dated:2012-12-14

Client: Changzhou EGING Photovoltaic Technology CO., Ltd.  
18th Jingwu Road, Yaodang Town, Jintan City, Jiangsu Province, China.

Manufacturing place: Changzhou EGING Photovoltaic Technology CO., Ltd.  
18th Jingwu Road, Yaodang Town, Jintan City, Jiangsu Province, China.

Test address: Product: Photovoltaic modules  
Type: EG-240P60-C

Test specification: IEC 61215: 2005-04, Second Edition; EN 61215: 2005, partial, see below for details;  
IEC 61730-2: 2004-10, First Edition; EN 61730-2: 2007, partial, see below for details;  
IEC 62169: 2009-01, System voltage durability test for crystalline silicon modules - Qualification and type approval

Purpose of examination: Test according to the test specifications.

Test result: The test results show that the presented product is in compliance with the specified requirements.

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Check condition:  
Add value:

TABLE: Wet leakage current test (final)

A2	-1000	P
A3	-1000	P
B2	-1000	P
B3	-1000	P

Supplementary information: NA

TABLE: Maximum power determination (final)

Sample No.	Measured [mW]	Limit [mW]	Verdict
A1	1207	24.54	P
A2	415	24.54	P
A3	491	24.54	P
B1	1091	24.54	P
B2	463	24.54	P
B3	416	24.54	P

Supplementary information: Size of module [m<sup>2</sup>]: 1.63

TABLE: Minimum power determination (final)

Sample #	Voc [V]	Vmp [V]	Isc [A]	Imp [A]	FF [%]	Pmp [mW]	Degradation [%]
A1	37.255	30.121	8.663	8.096	75.55	243.845	0
A2	37.221	30.209	8.659	8.050	75.45	243.195	0.26
A3	37.173	30.190	8.657	8.074	75.45	243.759	0.26
B1	37.160	30.113	8.653	8.059	75.42	242.642	0
B2	37.259	30.259	8.670	8.070	75.59	244.259	0.16
B3	37.277	30.326	8.640	8.069	75.96	245.312	0.13

Supplementary information: Crystalline silicon module; Pmp degradation after test = 5%

ロングラン・メーカー保障

合格

10年 システム保証

10年 システム保証

25年 出力保証

25年 出力保証

製品の材料および加工技術については10年保証  
ISO9001:2008品質マネジメントシステム認証工場  
IEC61215およびIEC61730認証製品

出力保証が12年間は最小ピーク電力の90%以上であること、また、25年間は80%以上であることを保証します。